

TOSHIBA Insulated Gate Bipolar Transistor Silicon N Channel IGBT

GT50J327

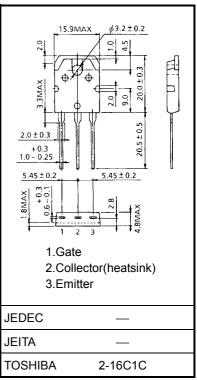
Current Resonance Inverter Switching Application

Unit: mm

- Enhancement mode type
- High speed : $t_f = 0.19 \mu s$ (typ.) (IC = 50A)
- Low saturation voltage: VCE (sat) = 1.9 V (typ.) (IC = 50A)
- FRD included between emitter and collector
- Fourth generation IGBT
- TO-3P(N) (Toshiba package name)

Maximum Ratings (Ta = 25°C)

Characteristics		Symbol	Rating	Unit	
Collector-emitter voltage		V _{CES}	600	V	
Gate-emitter voltage		V_{GES}	±25	V	
Continuous collector current	@ Tc = 100°C	la	29	А	
	@ Tc = 25°C	IC	50		
Pulsed collector current		I _{CP}	100	Α	
Diode forward current	DC	I _F	20	Α	
	Pulsed	I _{FP}	40		
Collector power dissipation	@ Tc = 100°C	D-	56	W	
	@ Tc = 25°C	P _C	140		
Junction temperature		Tj	150	°C	
Storage temperature range		T _{stg}	-55 to 150	°C	



Weight: 4.6 g (typ.)

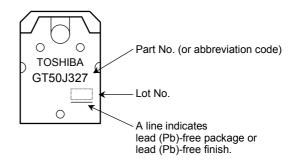
Thermal Characteristics

Characteristics	Symbol	Max	Unit
Thermal resistance (IGBT)	R _{th (j-c)}	0.89	°C/W
Thermal resistance (diode)	R _{th (j-c)}	2.7	°C/W

Equivalent Circuit

Gate O Collector

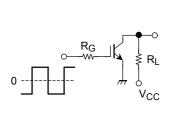
Marking

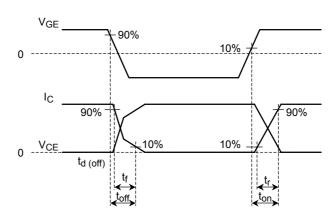


Electrical Characteristics (Ta = 25°C)

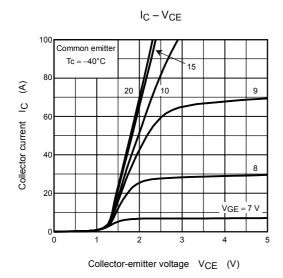
Chara	acteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Gate leakage current		I _{GES}	V _{GE} = ±25 V, V _{CE} = 0	_	_	±500	nA
Collector cut-off current		I _{CES}	V _{CE} = 600 V, V _{GE} = 0	_	_	1.0	mA
Gate-emitter cut-off voltage		V _{GE} (OFF)	I _C = 50 mA, V _{CE} = 5 V	3.0	_	6.0	V
Collector-emitter saturation voltage		V _{CE (sat)}	I _C = 50 A, V _{GE} = 15 V	_	1.9	2.3	V
Input capacitance		C _{ies}	V _{CE} = 10 V, V _{GE} = 0, f = 1 MHz	_	2500	_	pF
Switching time	Rise time	t _r	Resistive Load	_	0.20	_	- μs
	Turn-on time	t _{on}	V _{CC} = 300 V, I _C = 50 A	_	0.27	_	
	Fall time	t _f	V_{GG} = ±15 V, R_{G} = 39 Ω	_	0.19	0.32	
	Turn-off time	t _{off}	(Note 1)	_	0.44	_	
Diode forward voltage V		V _F	I _F = 15 A, V _{GE} = 0	_	_	2.0	V
Reverse recovery time		t _{rr}	I _F = 15 A, di/dt = -100 A/μs	_	_	0.2	μs

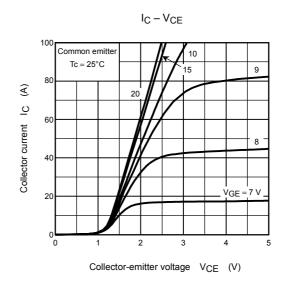
Note 1: Switching time measurement circuit and input/output waveforms

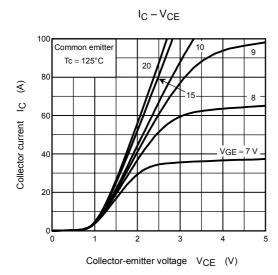


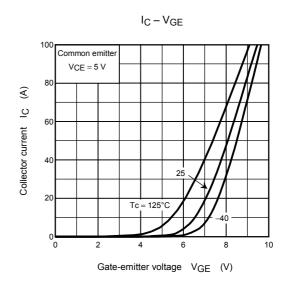


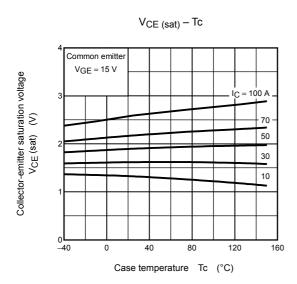
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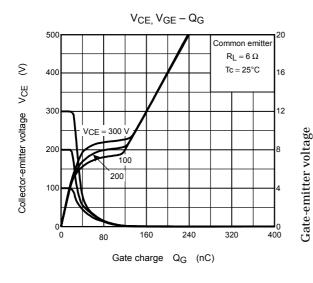


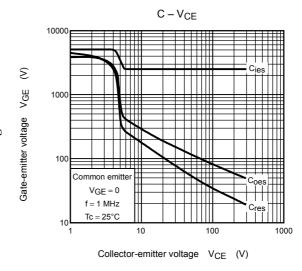


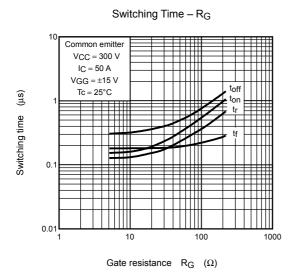


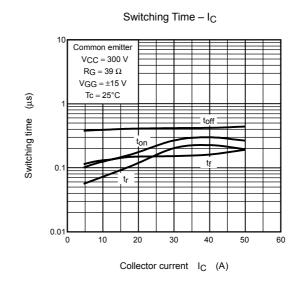


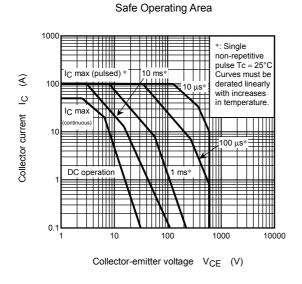
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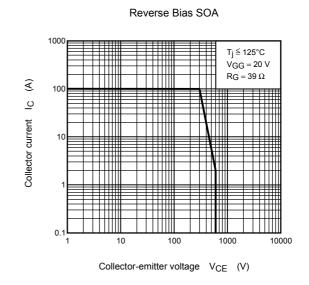




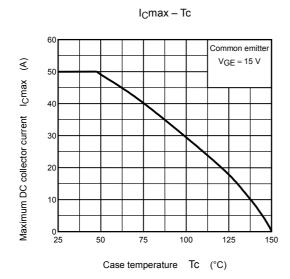


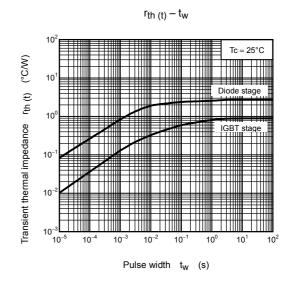


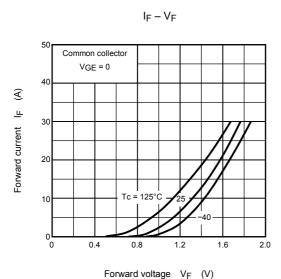


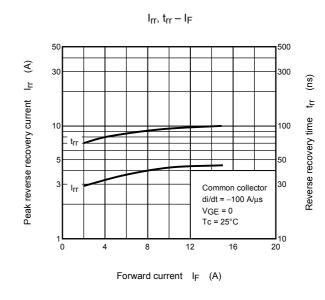


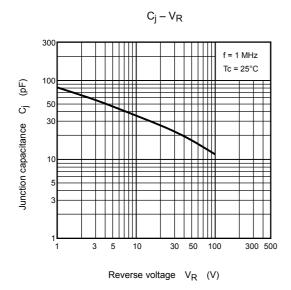
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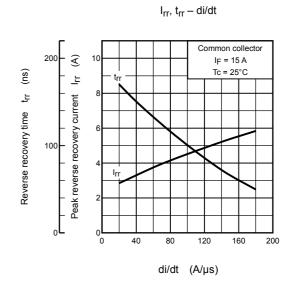












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